



Description

The NTMS4917NR2G uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



SOP-8

General Features

$V_{DS} = 30V$ $I_D = 10A$

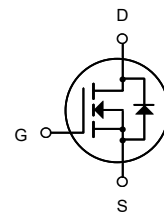
$R_{DS(ON)} < 12m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Ordering Information

Product ID	Pack	Brand	Qty(PCS)
NTMS4917NR2G	SOP-8	HXY MOSFET	3000

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	10.0	A
I_{DM}	Pulsed Drain Current	40	A
P_D	Maximum Power Dissipation	2.2	W
E_{AS}	Single pulse avalanche energy	17	mJ
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 150	°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Case	57	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
BV_{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	---	---	V
I_{DSS}	Zero Gate Voltage Drain Current	V _{GS} =0V, V _{DS} =30V	---	---	1	μA
I_{GSS}	Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0A	---	---	±100	nA
V_{GS(th)}	Gate-Source Threshold Voltage	V _{GS} =V _{DS} , I _D =250μA	1	1.4	2.5	V
R_{DS(on)}	Drain-Source On Resistance	V _{GS} =10V, I _D =10A	---	9	12	mΩ
		V _{GS} =4.5V, I _D =5A	---	15	20	mΩ
C_{iss}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	---	580	---	pF
C_{oss}	Output Capacitance		---	110	---	
C_{rss}	Reverse Transfer Capacitance		---	94	---	
t_{d(on)}	Turn-On Delay Time	V _{DS} =30V, I _D =20A, R _G =3Ω, V _{GS} =10V	---	4	---	ns
t_r	Rise Time		---	7	---	ns
t_{d(off)}	Turn-Off Delay Time		---	20	---	ns
t_f	Fall Time		---	6	---	ns
Q_g	Total Gate Charge	V _{GS} =4.5V, V _{DS} =15V, I _D =10A	---	8	---	nC
Q_{gs}	Gate-Source Charge		---	4.6	---	nC
Q_{gd}	Gate-Drain "Miller" Charge		---	3.5	---	nC
I_S	Continuous Drain Current	V _D =V _G =0V	---	---	10	A
I_{SM}	Diode pulsed current	V _D =V _G =0V	---	---	40	A
V_{SD}	Source-Drain Diode Forward Voltage	V _{GS} =0V, I _S =10A	---	---	1.2	V
Q_{rr}	Reverse Recovery Charge	I _S =20A, di/dt=100A/us	---	5.9	---	nC
T_{rr}	Reverse Recovery Time		---	7	---	ns

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
2. EAS condition: T_J=25°C, V_{DD}=15V, V_G=10V, L=0.5mH
3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%



Typical Characteristics

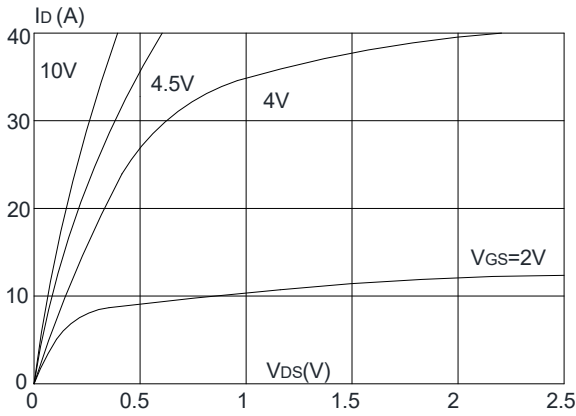


Figure 1: Output Characteristics

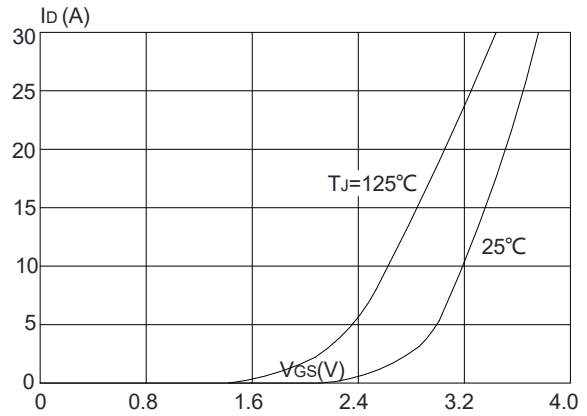


Figure 2: Typical Transfer Characteristics

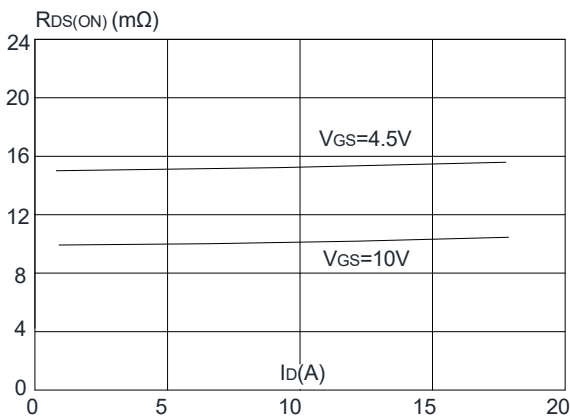


Figure 3: On-resistance vs. Drain Current

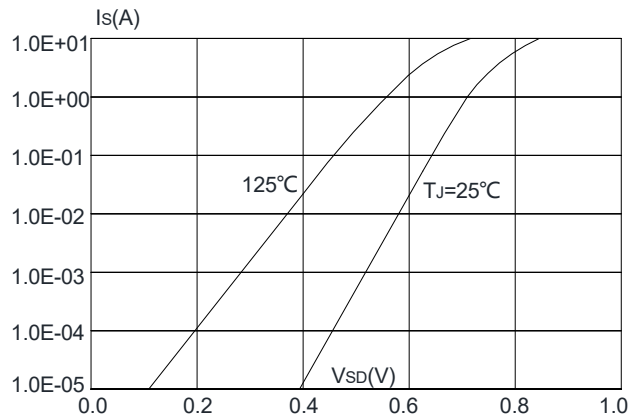


Figure 4: Body Diode Characteristics

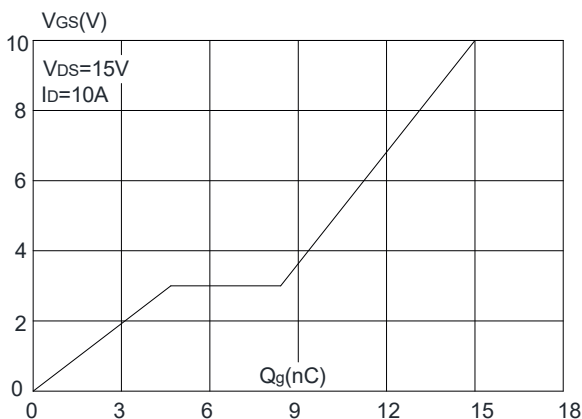


Figure 5: Gate Charge Characteristics

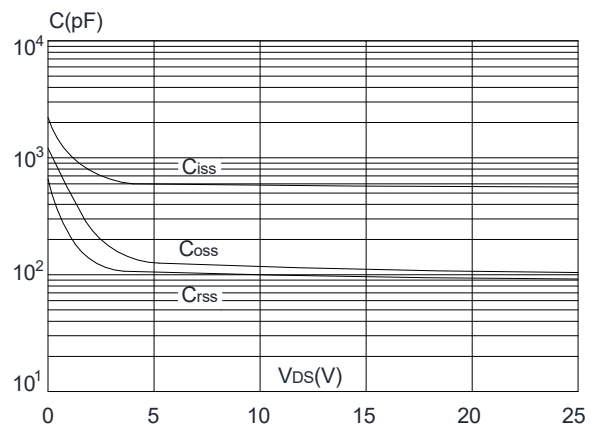


Figure 6: Capacitance Characteristics

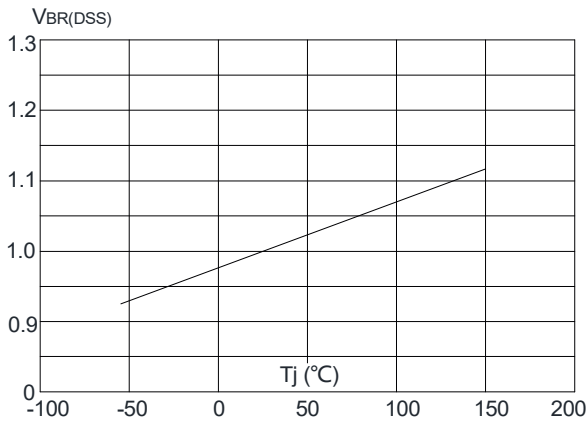


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

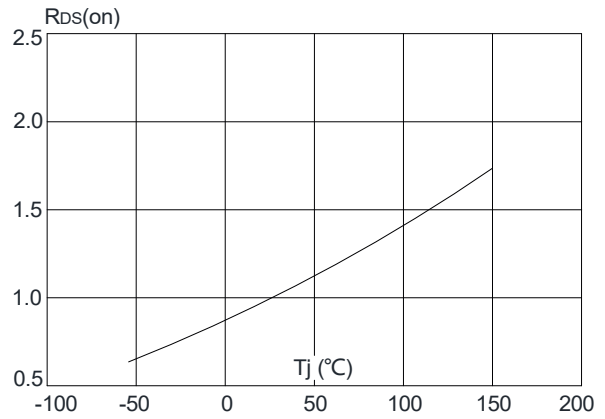


Figure 8: Normalized on Resistance vs. Junction Temperature

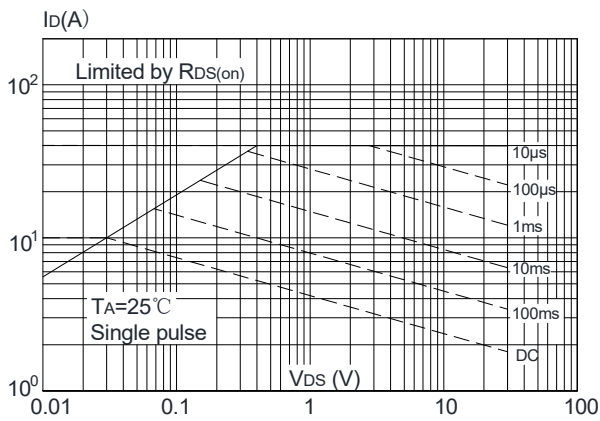


Figure 9: Maximum Safe Operating Area

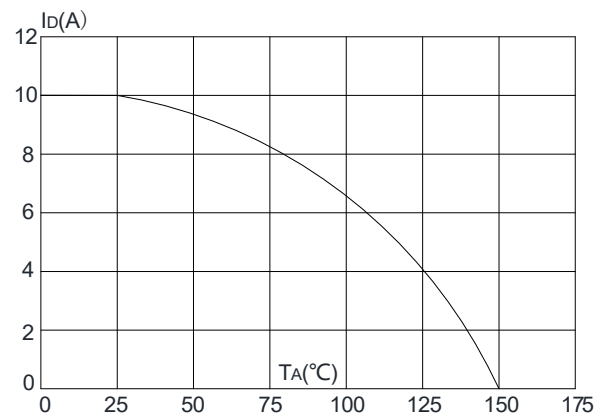


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

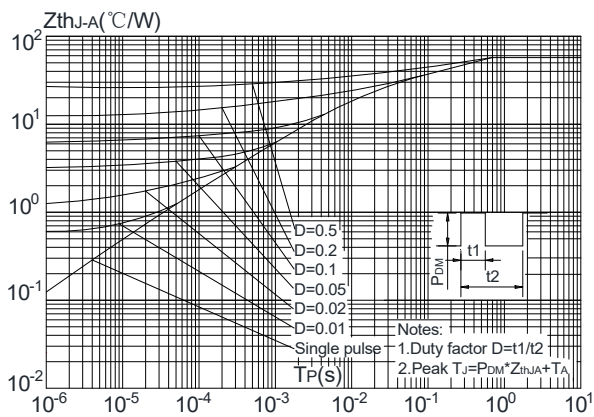


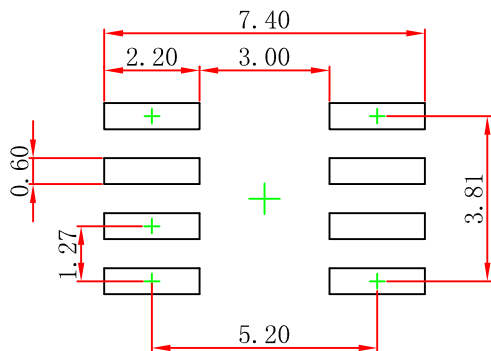
Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



SOP-8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.



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